

MJLP2951-X REV 1B1

 Original Creation Date: 08/01/95
 Last Update Date: 05/19/98
 Last Major Revision Date: 01/21/97

ADJUSTABLE MICROPPOWER VOLTAGE REGULATORS
General Description

The LP2951 is a micropower voltage regulator with very low quiescent current (75 uA typ.) and very low dropout voltage (typ. 40 mV at light loads and 380 mV at 100mA). They are ideally suited for use in battery-powered systems. Furthermore, the quiescent current of the LP2951 increases only slightly in dropout, prolonging battery life.

The 8-Lead LP2951 is available in plastic, ceramic dual-in-line, or metal can packages and offers additional system functions.

One such feature is an error flag output which warns of a low output voltage, often due to falling batteries on the input. It may be used for a power-on reset. A second feature is the logic-compatible shutdown input which enables the regulator to be switched on and off. Also, the part may be pin-strapped for a 5V output or programmed from 1.24V to 29V with an external pair of resistors.

Careful design of the LP2951 has minimized all contributions to the error budget. This includes a tight initial tolerance (.5% typ.), extremely good load and line regulation (.05% typ.) and a very low output voltage temperature coefficient, making the part useful as a low-power voltage reference.

Industry Part Number

LP2951

NS Part Numbers

 JL2951BGA*
 JL2951BPA**
 JL2951S2A***
 JL2951SGA****
 JL2951SPA*****

Prime Die

LP2951

Controlling Document

See Features Page REV C

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description
Temp (°C)

1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- SMD : 5962-3870501BGA*, BPA**, S2A***, SGA****, SPA*****.

(Absolute Maximum Ratings)

(Note 1)

Power Dissipation

(Note 2)

METAL CAN	675mW at +25 C
CERDIP	1.0W at +25 C
LCC	1.25W at +25 C
CERAMIC SOIC	1.0W at +25 C

Lead Temperature

(Soldering, 10 seconds)

260 C

Storage Temperature Range

-65 C to +150 C

Operating Junction Temp Range

LP2951

-55 C to +160 C

Input Supply Voltage

-0.3 to +30V

Feedback Input Voltage

(Note 3, 4)

-1.5 to +30V

Shutdown Input Voltage

(Note 3)

-0.3 to +30V

Error Comparator Out. Voltage

(Note 3)

-0.3 to +30V

Thermal Resistance

ThetaJA

METAL CAN	(Still Air @ 0.5W)	163 C/W
	(500LF/Min Air flow @ 0.5W)	95 C/W
CERDIP	(Still Air @ 0.5W)	131 C/W
	(500LF/Min Air flow @ 0.5W)	75 C/W
LCC	(Still Air @ 0.5W)	95 C/W
	(500LF/Min Air flow @ 0.5W)	66 C/W
CERAMIC SOIC	(Still Air @ 0.5W)	215 C/W
	(500LF/Min Air flow @ 0.5W)	130 C/W

ThetaJC

METAL CAN	51 C/W
CERDIP	21 C/W
LCC	24 C/W
CERAMIC SOIC	24 C/W

Package Weight

(Typical)

TBD

ESD Rating

500V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{dmax} = (T_{jmax} - T_A) / \Theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.

Note 3: May exceed input supply voltage.

Note 4: When used in dual-supply systems where the output terminal sees loads returned to a negative supply, the output voltage should be diode-clamped to ground.

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{out} = 5V$ (Nominal), $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$, $V_{in} = 6V$, $I_l = -100\mu A$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
V_o	Output Voltage	$V_{in} = 6V$, $I_l = -100\mu A$			4.975	5.025	V	1
					4.94	5.06	V	2, 3
V_{oline}	Line Regulation	$6V \leq V_{in} \leq 30V$, $I_l = -1mA$			-5	5	mV	1
		$6V \leq V_{in} \leq 30V$, $I_l = -1mA$			-25	25	mV	2, 3
V_{oload}	Load Regulation	$-100\mu A \leq I_l \leq -100mA$, $V_{in} = 6V$			-5	5	mV	1
		$-100\mu A \leq I_l \leq -100mA$, $V_{in} = 6V$			-25	25	mV	2, 3
V_d	Dropout Voltage	$I_l = -100mA$				450	mV	1
						600	mV	2, 3
		$I_l = -100\mu A$				80	mV	1
						150	mV	2, 3
I_g	Ground Current	$I_l = -100mA$, $V_{in} = 6V$				12	mA	1
						14	mA	2, 3
		$I_l = -100\mu A$, $V_{in} = 6V$				120	uA	1
						140	uA	2, 3
		$I_l = -100\mu A$, $V_{out} = 15V$, $V_{in} = 30V$				120	uA	1
						140	uA	2, 3
		$I_l = -100\mu A$, $V_{in} = 30V$, $V_{out} = 15V$				15	mA	1
						20	mA	2, 3
I_{gdiff}	Ground Current Change	$6V \leq V_{in} \leq 30V$, $I_l = -100\mu A$			-30	30	uA	1
		$6V \leq V_{in} \leq 30V$, $I_l = -100\mu A$			-50	50	uA	2, 3
I_{gdo}	Dropout Ground Current	$V_{in} = 4.5V$, $I_l = -100\mu A$				170	uA	1
						200	uA	2, 3
V_{lt}	Error Comparator Lower Threshold Voltage	$V_{in} = 6V$, $I_l = -100\mu A$	1		0	0.8	mV	1, 2, 3
V_{ut}	Error Comparator Upper Threshold Voltage	$V_{in} = 6V$, $I_l = -100\mu A$	1		2	30	mV	1, 2, 3
V_{rth}	Thermal Regulation	$V_{in} = 30V$, $I_l = -50mA$, $2mS \leq T \leq 10mS$			-12.5	12.5	mV	1
I_{sc}	Current Limit	$V_{out} = 0V$, $V_{in} = 6V$				200	mA	1
						220	mA	2, 3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{out} = 5V$ (Nominal), $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$, $V_{in} = 6V$, $I_L = -100\mu A$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Igsc	Ground Current At Current Limit	$V_{out} = 0V$, $V_{in} = 6V$				20	mA	1
						25	mA	2, 3
Vref	Reference Voltage				1.22	1.25	V	1
					1.20	1.26	V	2, 3
Vrline	Reference Voltage Line Regulation	$2.3V \leq V_{in} \leq 30V$			-1.9	1.9	mV	1
		$2.3V \leq V_{in} \leq 30V$			-10	10	mV	2, 3
Vrload	Reference Voltage Output Regulation	$1.2V \leq V_{out} \leq 29V$, $V_{in} = 30V$			-1.2	1.2	mV	1
		$1.2V \leq V_{out} \leq 29V$, $V_{in} = 30V$			-5	5	mV	2, 3
Ifb	Feedback Pin Bias Current					40	nA	1
						60	nA	2, 3
Ioh	Error Comparator Output Leakage Current	$V_o = 30V$				1	uA	1
						2	uA	2, 3
Vol	Error Comparator Output Low Voltage	$V_{in} = 4.5V$, $V_{sd} = 2V$				250	mV	1
						400	mV	2, 3
Isd	Shutdown Pin Input Current	$V_{sd} = 2.4V$				50	uA	1
						100	uA	2, 3
		$V_{sd} = 30V$				600	uA	1
						750	uA	2, 3
Vsdl	Shutdown Input Logic Voltage	(LOW)	1			0.6	V	1, 2, 3
Vsdh	Shutdown Input Logic Voltage	(HIGH)	1		2		V	1, 2, 3
Ilkg	Regular Output Bias Current In Shutdown	$V_{sd} = 2V$, $V_{in} = 30V$, $I_L = 0mA$			-10	10	uA	1
					-20	20	uA	2, 3

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

AC: $V_{in} = 6V$, $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$

Rr	Ripple Rejection	$f = 120Hz$, $V_{in} = 0.1V_{rms}$			50		dB	4
Vnoise	Output Noise	$C_1 = 1\mu F$				600	uVrms	7
		$C_1 = 3.3\mu F$				250	uVrms	7

Electrical Characteristics

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: Vout = 5V (Nominal), Cload = 3.3uF, Vsd = 0.6V, Vin = 6V, Il = -100uA. "Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 ONLY."

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Ig	Ground Current	Il = -100uA, Vin = 6V			-6.5	6.5	uA	1
Vref	Reference Voltage				-0.0055	0.0055	V	1

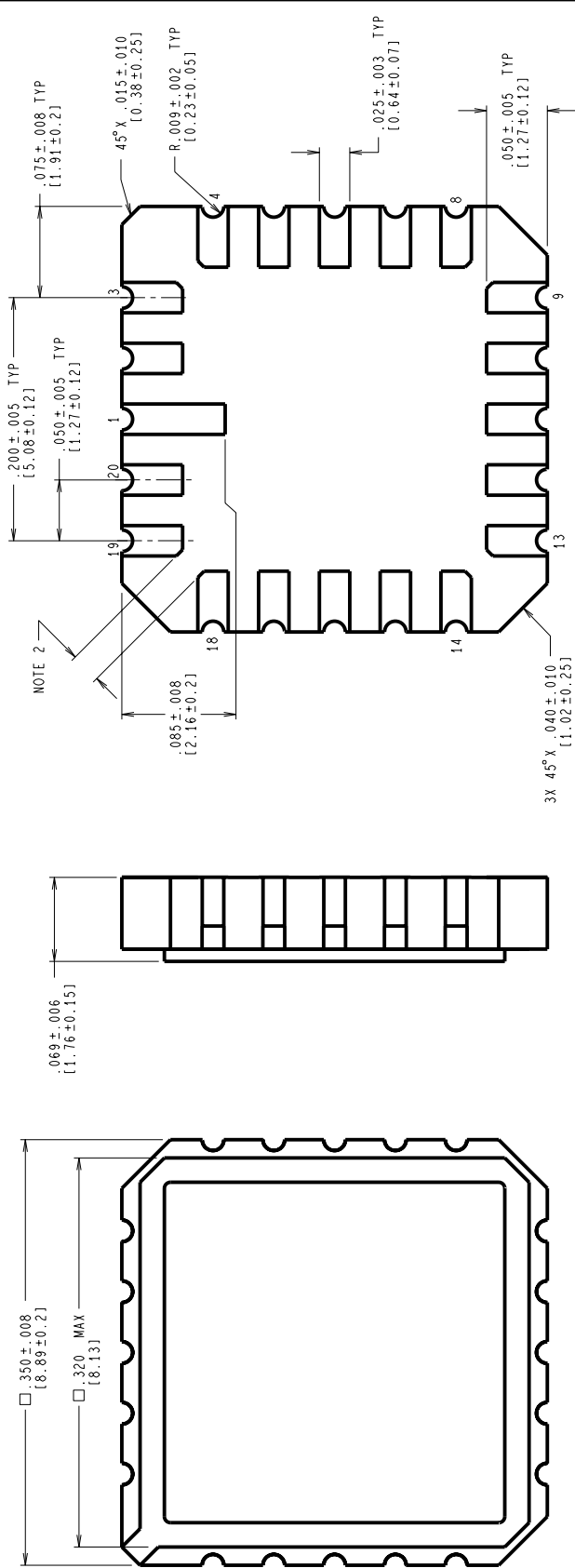
Note 1: Parameter tested go-no-go only.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05810HRA2	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (B/I CKT)
06059HRA2	CERDIP (J), 8 LEAD (B/I CKT)
06146HRA2	LCC (E), TYPE C, 20 TERMINAL(B/I CKT)
06341HRA1	CERPACK (W), 10 LEAD (B/I CKT)
E20ARE	LCC (E), TYPE C, 20 TERMINAL(P/P DWG)
H08CRF	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (P/P DWG)
J08ARL	CERDIP (J), 8 LEAD (P/P DWG)
P000205A	METAL CAN (H), 8 LEAD (PINOUT)
P000206A	CERDIP (J), 8 LEAD (PINOUT)
P000251B	LCC (E), 20 LEAD (PINOUT)
P000374A	CERAMIC SOIC (WG), 10 LEAD (PINOUT)
WG10ARC	CERAMIC SOIC (WG), 10 LEAD (P/P DWG)

See attached graphics following this page.

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
E	REVISE AND REDRAW	10005	02/10/94 DEG/



CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

NOTES: UNLESS OTHERWISE SPECIFIED.

1. LEAD FINISH TO BE ONE OF THE FOLLOWING:

a. 50 MICRONS/12.7 MICROMETERS MINIMUM GOLD PLATING OVER 50-350 MICRONS/1.27-8.89 MICROMETERS NICKEL.

b. SOLDER DIP.
SOLDER THICKNESS PER LATEST REVISION OF MIL-STD-1835.

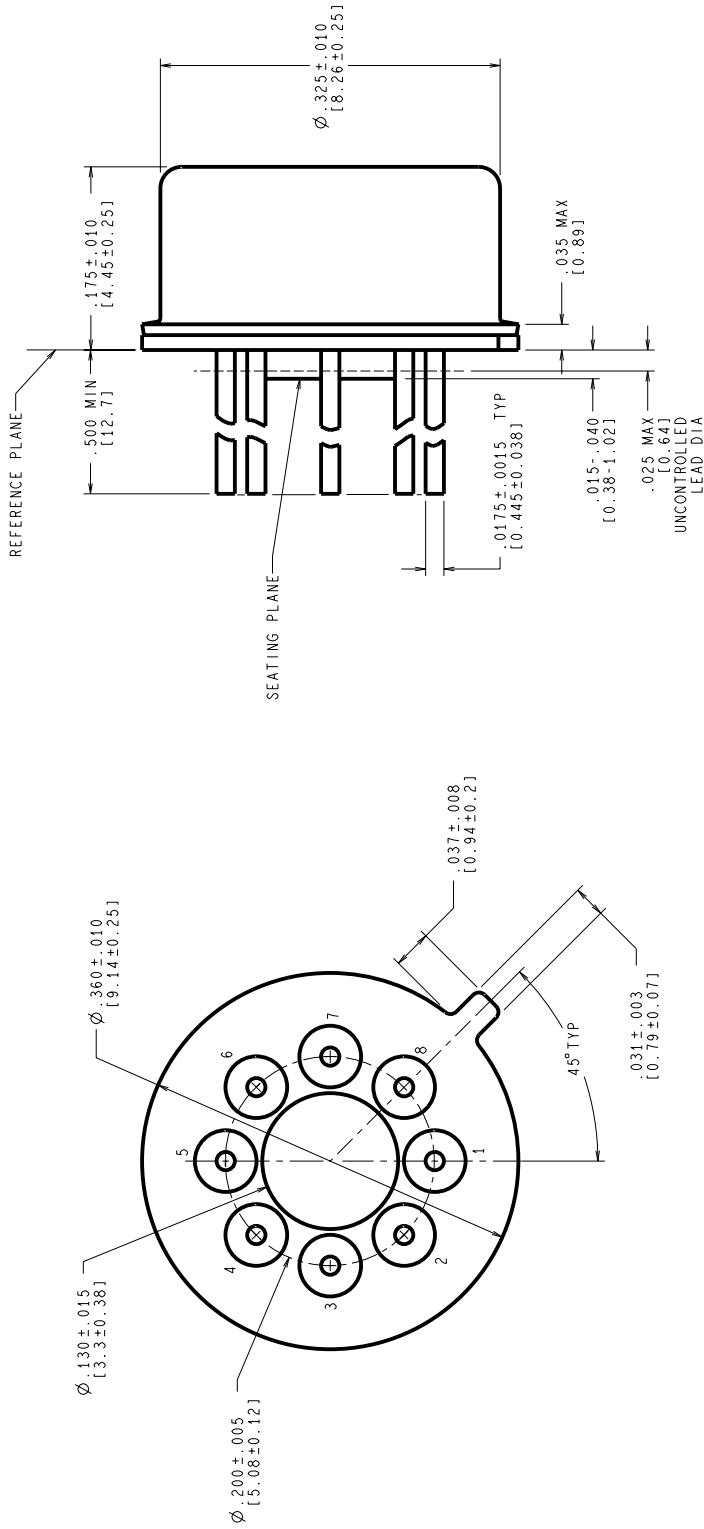
2. CORNER PADS MAY HAVE A 45° X $.020$ IN/0.51mm MAXIMUM CHAMFER TO ACCOMPLISH THE .015 IN/0.38mm DIMENSION.

4. REFERENCE JEDEC REGISTRATION MS-004, VARIATION CB, DATED 7/90.

MIL/AERO CONFIGURATION CONTROL

APPROVALS		DATE	NATIONAL SEMICONDUCTOR CORPORATION	
DESIGN	Design Grady	02/10/94	2000 Semiconductor Drive, Santa Clara, CA 95052-8000	
ESTG. CHK.			LEADLESS CHIP CARRIER, TYPE C, 20 TERMINAL	
ENGR. CHK.				
APPROVAL				
PROJECTION			SCALE	SIZE
			N/A	C
			DO NOT SCALE	DRAWING
			REV	REV
			MKT-E20A	E
			SHEET 1 of 1	

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
F	REVISE & REDRAW PER CURRENT STANDARD; UPDATE MIL/AERO STAMP & TITLE.	11002	06/22/95
			MS/



CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

MIL-I-38535
CONFIGURATION CONTROL

NOTES: UNLESS OTHERWISE SPECIFIED

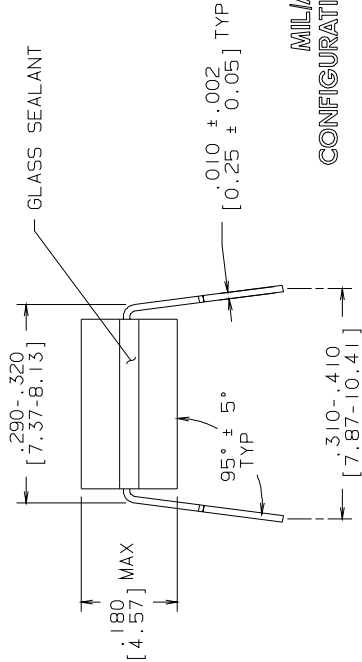
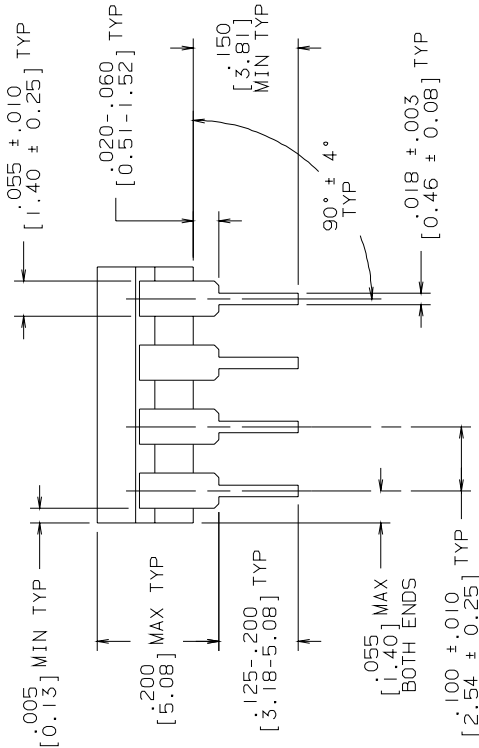
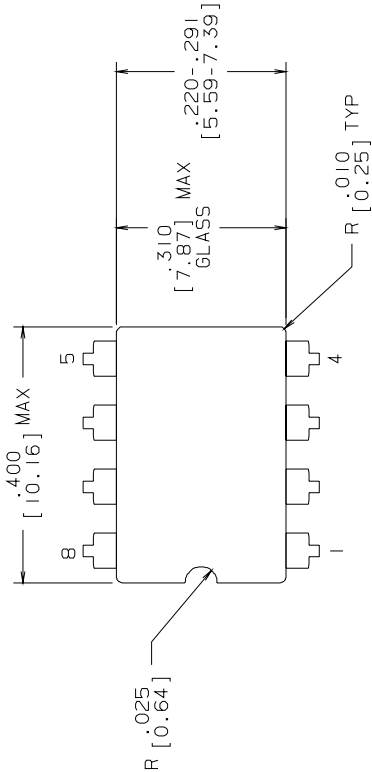
- LEADS TO BE LOCATED WITHIN .007 IN/ 0.18 mm OF THEIR TRUE POSITIONS RELATIVE TO A MAXIMUM WIDTH TAB.
- STANDARD METAL CAN TYPE: SOLID BASE WITH CERAMIC STANDOFF.
- APPLIES TO MIL-AERO AND LINEAR PRODUCTS.
- REFERENCE JEDEC REGISTRATION TO-99, JEDEC PUBLICATION No. 95.

APPROVALS		DATE
DESIGN	MARIA SUCHY	06/22/95
DFTG	CHK	
ENGR	CHK	
PROJECTION		
SCALE		N/A
SIZE		C
DRAWING NUMBER		MKT-H08C
REV		F
DO NOT SCALE DRAWING		SHEET 1 of 1

National Semiconductor
2000 Semiconductor dr., Santa Clara, CA 95052-8000

**METAL CAN,
TO-99, 8 LEAD,
.200 DIA P.C.**

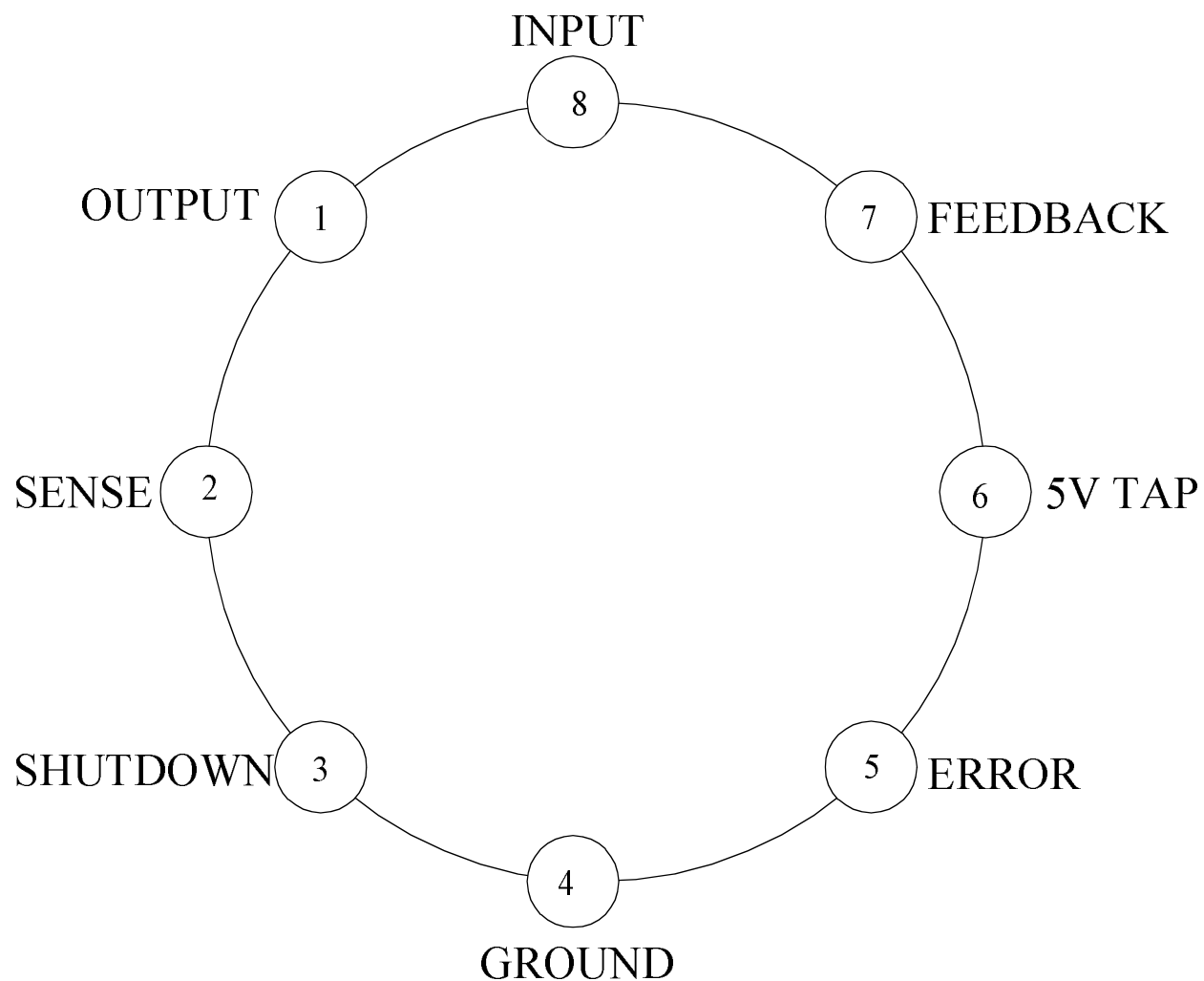
R E V I S I O N S				
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
L	REVISE PER CURRENT STD; REDRAW	10002	09/21/93	TL/



MIL-AERO
CONFIGURATION CONTROL
MIL-M-38510
CONFIGURATION CONTROL

CONTROLLING DIMENSION: INCH				
APPROVALS	DATE	NATIONAL SEMICONDUCTOR CORPORATION		
DRAWN LEQUANG	09/21/93	2900 Semiconductor Drive, Santa Clara, CA 95052-8090		
DFTG. CHK.		CERDIP (J) , 8 LEAD		
ENGR. CHK.				
APPROVAL				
 PROJECTION 1 INCH [25.4]	SCALE	SIZE	DRAWING NUMBER	REV
	N/A	B	MKT-J08A	L
DO NOT SCALE DRAWING		SHEET	1	OF 1

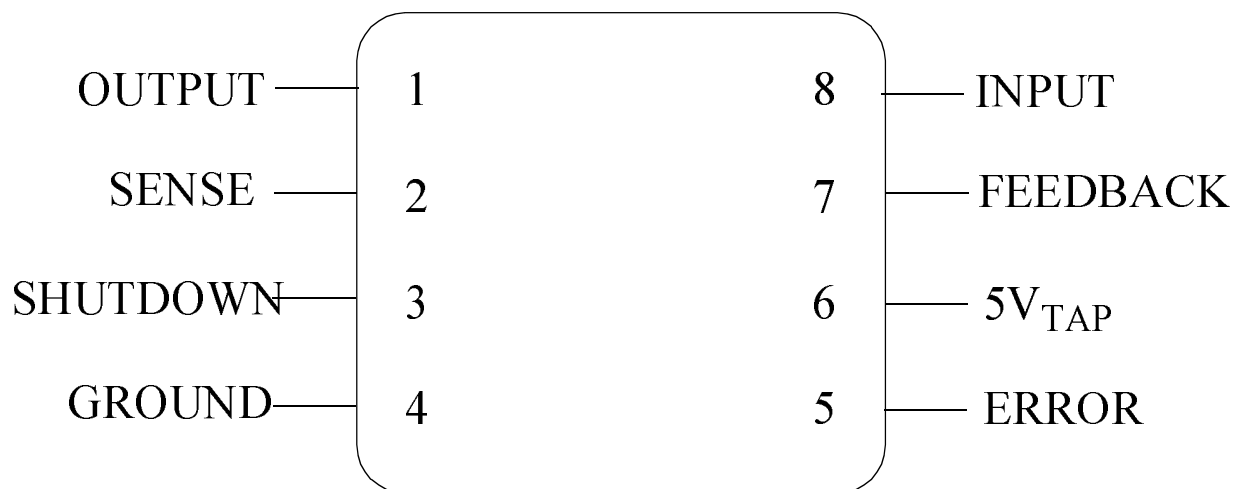
- NOTES: UNLESS OTHERWISE SPECIFIED
1. LEAD FINISH TO BE 200 MICRONS / 5.08 MICROMETERS MINIMUM SOLDER MEASURED AT THE CREST OF THE MAJOR FLATS.
 2. JEDEC REGISTRATION MO-036, VARIATION AA, DATED 04/1981.



LP2951H
8 - PIN METAL CAN
CONNECTION DIAGRAM
TOP VIEW
P000205A



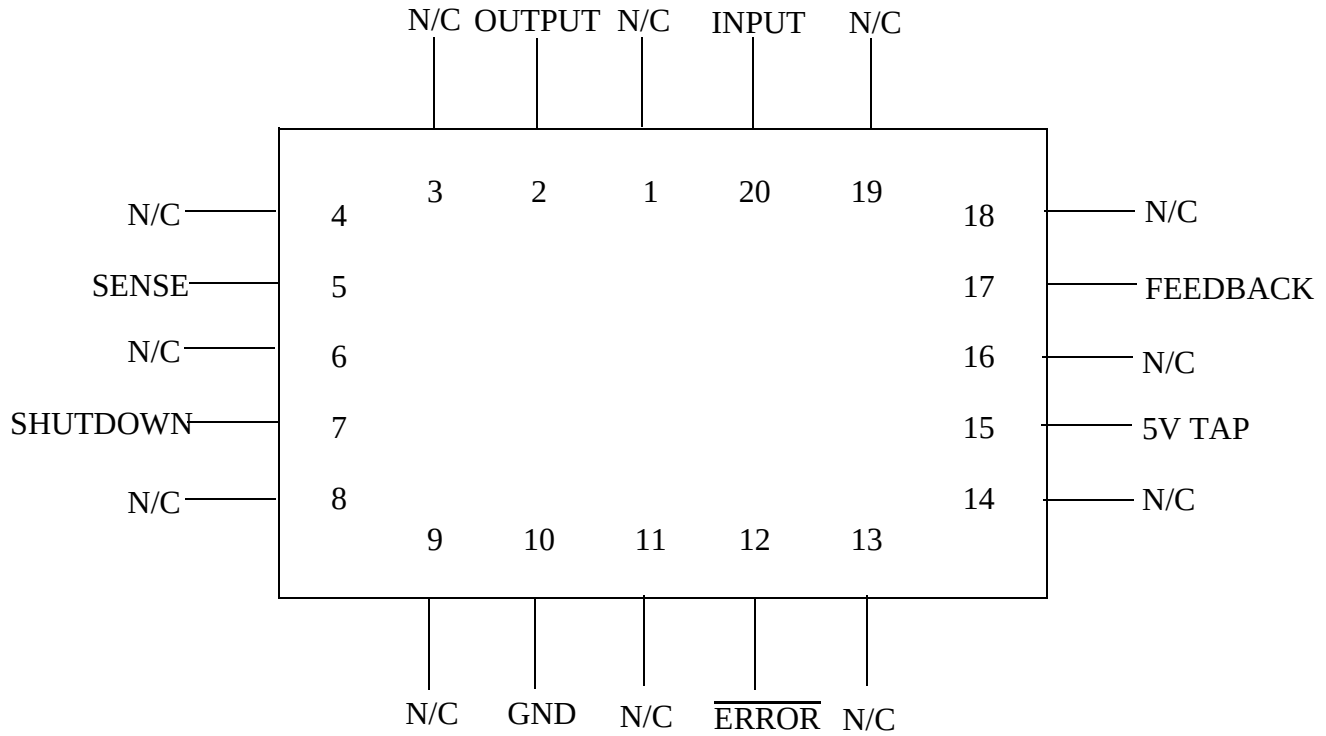
National Semiconductor™
MIL/AEROSPACE OPERATIONS
2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050



LP2951J
8 - LEAD DIP
CONNECTION DIAGRAM
TOP VIEW
P000206A



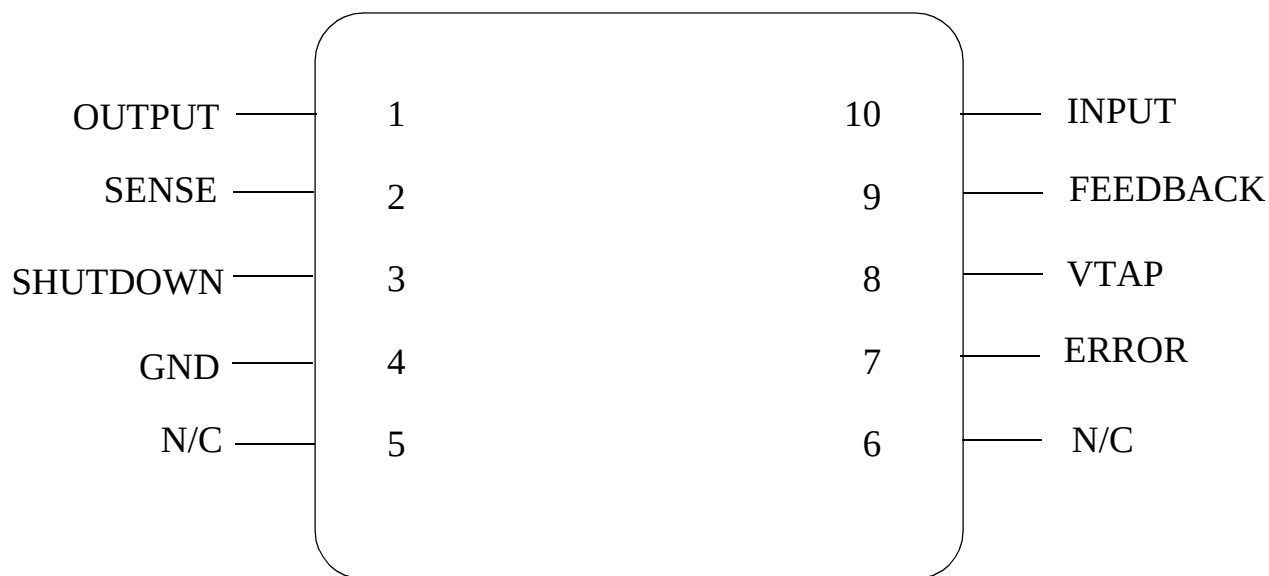
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2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050



LP2951E
20 - LEAD LCC
CONNECTION DIAGRAM
TOP VIEW
P000251B



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MIL/AEROSPACE OPERATIONS
2900 SEMICONDUCTOR DRIVE
SANTA CLARA, CA 95050



LP2951WG
10 - LEAD CERAMIC SOIC
CONNECTION DIAGRAM
TOP VIEW
P000374A

Revision History

Rev	ECN #	Rel Date	Originator	Changes
1B1	M0002867	05/19/98	Barbara Lopez	Update MDS: MJLP2951-X Rev. 1A0 to MJLP2951-X Rev. 1B1. Updated SMD number to add suffixes. Updated NSID to add astericks associated with SMD suffix. Updated power dissipation, lead temperature, junction temperature, thermal resistance and ESD rating. Changed note 1 to Absolute note, updated note 2 to power dissipation note. Added graphics for all packages. Added Package Weights.